TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

# TC7W53FU, TC7W53FK

#### 2-Channel Multiplexer/Demultiplexer

The TC7W53 is a high speed  $C^2MOS$  Analog Multiplexer/ Demultiplexer fabricated with silicon gate  $C^2MOS$  technology. It achieves the high speed operation similar to equivalent LSTTL while maintaining the  $C^2MOS$  low power dissipation. The TC7W53 has a 2 channel configuration.

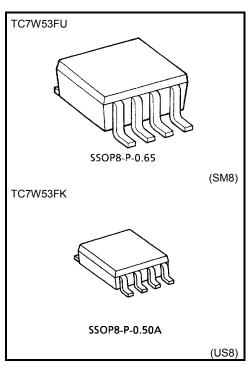
The digital signal to the control terminal turns "ON" the corresponding switch of each channel a large amplitude signal ( $V_{\rm CC}-V_{\rm EE}$ ) can then be switched by the small logical amplitude ( $V_{\rm CC}-G_{\rm ND}$ ) control signal.

For example, in the case of  $V_{\rm CC}=5$  V, GND=0 V,  $V_{\rm EE}=-5$  V, signals between -5 V and +5 V can be switched from the logical circuit with a signal power supply of 5 V. As the ON-resistance of each switch is low, they can be connected to circuit with low input impedance.

All inputs are equipped with protection circuits against static discharge or transient excess voltage.

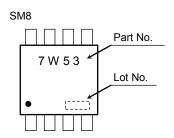
#### **Features**

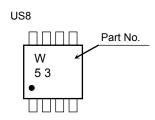
- High speed:  $t_{pd} = 15 \text{ ns (typ.)}$  at  $V_{CC} = 5 \text{ V}$ ,  $V_{EE} = 0 \text{ V}$
- Low power dissipation:  $I_{CC} = 4 \mu A \text{ (max)}$  at  $T_a = 25 \text{°C}$
- High noise immunity: VNIH = VNIL = 28% VCC (min)
- Low ON resistance:  $RON = 50 \Omega$  (typ.) at VCC-VEE = 9 V
- High degree of linearity: THD = 0.02% (typ.) at V<sub>CC</sub>-V<sub>EE</sub> =9 V
- Pin and function compatible with TC4W53



Weight SSOP8-P-0.65: 0.02 g (typ.) SSOP8-P-0.50A: 0.01 g (typ.)

## Marking





#### Absolute Maximum Ratings (Ta = 25°C)

Characteristics	Symbol	Rating	Unit	
Supply voltage range	V <sub>CC</sub>	–0.5 to 7	V	
Supply voltage range	V <sub>CC</sub> – V <sub>EE</sub>	−0.5 to 13		
Control input voltage	V <sub>IN</sub>	$-0.5$ to $V_{CC} + 0.5$	<b>V</b>	
Switch I/O voltage	V <sub>I/O</sub>	$V_{EE}$ $-0.5$ to $V_{CC}$ + $0.5$	V	
Control input diode current	Ick	±20	mA	
I/O diode current	I <sub>IOK</sub>	±20	mA	
Switch through current	Ι <sub>Τ</sub>	±25	mA	
DC V <sub>CC</sub> /GND current	Icc	±25	mA	
Dower discipation	D-	300 (SM8)	mW	
Power dissipation	P <sub>D</sub>	200 (US8)		
Storage temperature range	T <sub>stg</sub>	-65 to 150	°C	
Lead temperature (10 s)	TL	260	°C	

Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges.

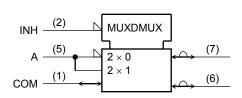
Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/"Derating Concept and Methods") and individual reliability data (i.e. reliability test report and estimated failure rate, etc).

#### **Truth Table**

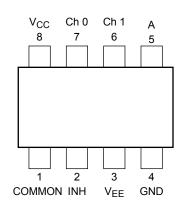
Contro	I Input	On Channel
INH	Α	On Channel
L	L	Ch 0
L	Н	Ch 1
Н	Х	None

X: Don't care

#### **Logic Symbol**

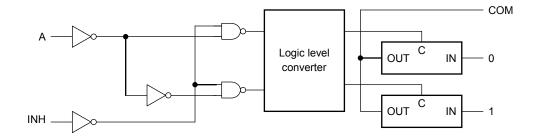


#### Pin Assignment (top view)





# Logic Diagram



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# **Operating Ranges**

Characteristics	Symbol	Rating	Unit	
	V <sub>CC</sub>	2 to 6		
Supply voltage	V <sub>EE</sub>	−6 to 0	V	
	V <sub>CC</sub> – V <sub>EE</sub>	2 to 12		
Control input voltage	V <sub>IN</sub>	0 to V <sub>CC</sub>	V	
Switch I/O voltage	V <sub>I/O</sub>	V <sub>EE</sub> to V <sub>CC</sub>	V	
Operating temperature range	T <sub>opr</sub>	-40 to 85	°C	
		0 to 1000 (V <sub>CC</sub> = 2.0 V)		
Input rise and fall time	t <sub>r</sub> , t <sub>f</sub>	0 to 500 (V <sub>CC</sub> = 4.5 V)	ns	
		0 to 400 (V <sub>CC</sub> = 6.0 V)		



## **Electrical Characteristics**

## **DC Electrical Characteristics**

Characte	eristics	Symbol Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit	
				V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	
			_	2.0	1.5	_	_	1.5	_		
	High level	V <sub>IHC</sub>	_	_	4.5	3.15	_	_	3.15	_	V
Control input					6.0	4.2	_		4.2	_	
voltage					2.0	_	_	0.5		0.5	V
	Low level	V <sub>ILC</sub>	_	_	4.5	_	_	1.35	_	1.35	
					6.0	_	_	1.8		1.8	
			V <sub>IN</sub> = V <sub>ILC</sub> or V <sub>IHC</sub>	GND	4.5	_	85	180		225	
			$V_{I/O} = V_{CC}$ to $V_{EE}$	-4.5	4.5	_	55	120	_	150	Ω
			$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0	_	50	100		125	
ON resistance		R <sub>ON</sub>	RON $V_{IN} = V_{ILC} \text{ or } V_{IHC}$ $V_{I/O} = V_{CC} \text{ or } V_{EE}$ $I_{I/O} \le 2 \text{ mA}$	GND	2.0	_	150		_	_	
				GND	4.5	_	70	150		190	
				-4.5	4.5	_	50	100	_	125	
				-6.0	6.0	_	45	80	_	100	
Difference of C	)NI		V <sub>IN</sub> = V <sub>ILC</sub> or V <sub>IHC</sub>	GND	4.5	_	10	30	_	35	
resistance bety		$\Delta R_{ON}$	$V_{I/O} = V_{CC}$ to $V_{EE}$	-4.5	4.5	_	5	12		15	Ω
switches			$I_{I/O} \le 2 \text{ mA}$	-6.0	6.0	_	5	10	_	12	
Input/output leakage			$V_{OS} = V_{CC}$ or GND	GND	6.0	_	_	±60	_	±600	
current (switch		l <sub>OFF</sub>	$V_{IS} = GND \text{ to } V_{CC}$ $V_{IN} = V_{ILC} \text{ or } V_{IHC}$	-6.0	6.0	_	_	±100	_	±1000	nA
Switch input le	akage	l	$I_{IZ} \qquad \begin{array}{c} V_{OS} = V_{CC} \text{ or GND} \\ V_{IN} = V_{ILC} \text{ or } V_{IHC} \end{array}$	GND	6.0	_	_	±60	_	±600	nA
(switch on outp	out open)	ΊΖ		-6.0	6.0	_	_	±100		±1000	11/4
Control input c	urrent	I <sub>IN</sub>	$V_{IN} = V_{CC}$ or GND	GND	6.0	_	_	±0.1	_	±1.0	μΑ
Quiocoopt our		V V or CND	GND	6.0	_	_	4	_	40		
Quiescent supp	piy current	Icc	$I_{CC}$ $V_{IN} = V_{CC}$ or GND	-6.0	6.0			8		80	μА



# AC Electrical Characteristics (C $_L$ = 50 pF, input $t_r$ = $t_f$ = 6 ns, GND = 0 V) $\,$

Characteristics Symbol		Test Condition			Ta = 25°C			Ta = -40 to 85°C		Unit
<b>-</b>	- Cy20.	rest condition	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Min	Тур.	Max	Min	Max	0
			GND	2.0		25	60		75	ns
Phase difference between	φΙ/О		GND	4.5		6	12	_	15	
input and output	ψι/Ο	_	GND	6.0		5	10		13	
			-4.5	4.5	_	4	_	_	_	
			GND	2.0		50	225		280	
Outrout available times	t <sub>pZL</sub>	D 4160	GND	4.5		14	45		56	ns
Output enable time	t <sub>pZH</sub>	$R_L = 1 \text{ k}\Omega$	GND	6.0		12	38		48	
			-4.5	4.5		14	_	_	_	
	t <sub>pLZ</sub> t <sub>pHZ</sub>	$R_L = 1 \text{ k}\Omega$	GND	2.0	_	95	225	_	280	ns
			GND	4.5	_	30	45	_	56	
Output disable time			GND	6.0	_	26	38	_	48	
			-4.5	4.5	_	26	_	_	_	
Control input capacitance	C <sub>IN</sub>	_	_	_	_	5	10	_	10	pF
Common terminal capacitance	C <sub>IS</sub>	_	-5.0	5.0	_	11	20	_	20	pF
Switch terminal capacitance	C <sub>OS</sub>		-5.0	5.0		7	15	_	15	pF
Feed through capacitance	C <sub>IOS</sub>	_	-5.0	5.0		0.75	2	_	2	pF
Power dissipation capacitance	C <sub>PD</sub>	(Note)	GND	5.0	_	67	_	_	_	pF

Note: C<sub>PD</sub> is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

Average operating current can be obtained by the equation:  $I_{CC \text{ (opr)}} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/2$ 



# Analog Switch Characteristics (GND = 0 V, Ta = 25°C)

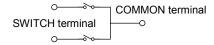
Characteristics	Symbol	Test Condition	V <sub>EE</sub> (V)	V <sub>CC</sub> (V)	Тур.	Unit				
		V <sub>IN</sub> = 4.0 V		4.0 Vp-p	-2.25	-2.25	0.025			
Sine wave distortion (T.H.D)	_	$R_L$ = 10 kΩ, $C_L$ = 50 pF $f_{IN}$ = 1 kHz	V <sub>IN</sub> =	V <sub>IN</sub> = 8.0 Vp-p		8.0 Vp-p -4.5		4.5	0.02	0.02 %
,			V <sub>IN</sub> =	11 Vp-p	-6.0	6.0	0.018			
				(Note1)	-2.25	-2.5	120	NAL I-		
				(Note2)	-2.23	-2.5	95			
Frequency response		Adjust V <sub>IN</sub> voltage to obtain 0dBm at V Increase F <sub>IN</sub> until dB Meter reads –3c	~~	(Note1)		4.5	190			
(switch ON)	t <sub>MAX</sub>	$R_L = 50 \ \Omega, \ C_L = 10 \ pF$ $f_{IN} = 1 \ MHz$ , sine wave		(Note2)	<del>-4</del> .5	4.5	150	MHz		
				(Note1)	0.0	0.0	200			
				(Note2)	-6.0	6.0	190			
	_	V <sub>IN</sub> is centered at (V <sub>CC</sub> -V <sub>EE</sub> )/2. Adjust	et innut t	for OdBm	-2.25	2.25	-50			
Feed Through attenuation (switch OFF)		$R_L = 600 \Omega$ , $C_L = 50 pF$	st input	ioi odbiii	-4.5	-4.5	-50	dB		
(6		f <sub>IN</sub> = 1 MHz, sine wave			-6.0	6.0	-50			
Crosstalk					-2.25	2.25	60			
(control input to signal	_	$R_L = 600~\Omega,~C_L = 50~pF \\ f_{IN} = 1~MHz,~square~wave~(t_r = t_f = 6~ns)$			-4.5 -4.5	140	mV			
output)					-6.0	6.0	200			
	Adjust V <sub>IN</sub> to obtain 0dBm at input			2.25	2.25	-50				
Crosstalk (between any switches)	_	$R_L = 600 \Omega$ , $C_L = 50 pF$			-4.5	-4.5	-50	dB		
, , , , , , , , , , , , , , , , , , , ,	f <sub>IN</sub> = 1 MHz, sine wave			6.0	6.0	-50				

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Note: These characteristics are determined by design of device.

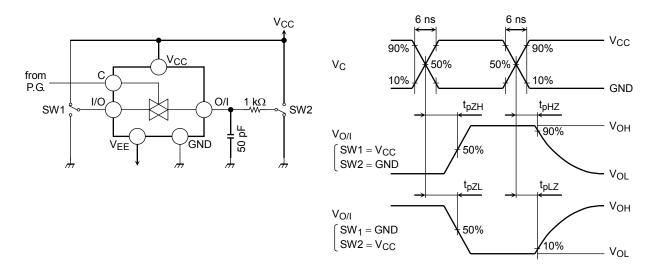
Note 1: Input COMMON terminal, and measure at SWITCH terminal.

Note 2: Input SWITCH terminal, and measure at COMMON terminal.

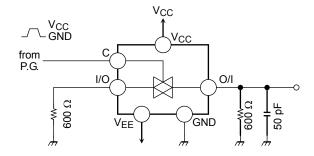


## **Switching Characteristics Test Circuits**

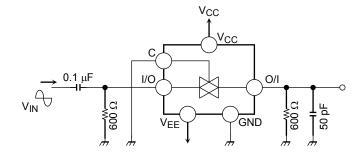
# 1. $t_{pLZ}$ , $t_{pHZ}$ , $t_{pZL}$ and $t_{pZH}$



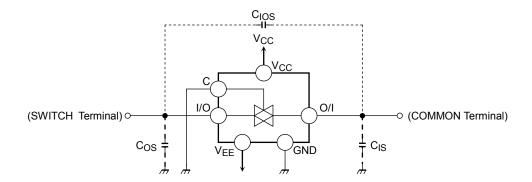
# 2. Cross Talk (control input-switch output) $f_{IN} = 1$ MHz, duty = 50% and $t_r = t_f = 6$ ns



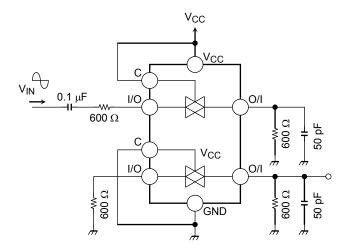
## 3. Feed Through Attenuation



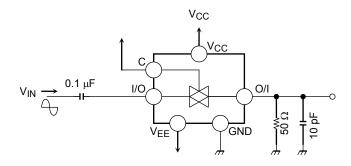
# 4. CIOS, CIS, COS



# 5. Cross Talk (between any two switches)



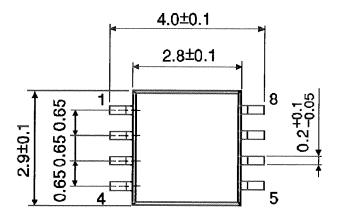
# 6. Frequency Response (switch ON)

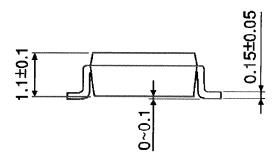


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# **Package Dimensions**

SSOP8-P-0.65 Unit: mm





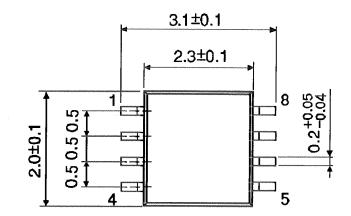
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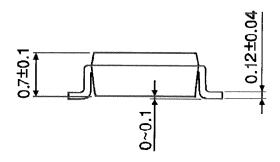
Weight: 0.02 g (typ.)

# **Package Dimensions**

SSOP8-P-0.50A







Weight: 0.01 g (typ.)

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